

Electrical Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)**Individual Component Characteristics**

Parameter	Test Conditions	Symbol	Device	Min	Typ	Max	Unit
EMITTER							
Input Forward Voltage	$I_F = \pm 10\text{ mA}$	V_F	All		1.2	1.5	V
Capacitance	$V_F = 0\text{ V}, f = 1.0\text{ MHz}$	C_J	All		80		pF
DETECTOR							
Breakdown Voltage Collector to Emitter	$I_C = 1.0\text{ mA}, I_F = 0$	BV_{CEO}	All	30			V
Collector to Base	$I_C = 100\text{ }\mu\text{A}, I_F = 0$	BV_{CBO}	All	70			V
Emitter to Base	$I_E = 100\text{ }\mu\text{A}, I_F = 0$	BV_{EBO}	All	5			V
Emitter to Collector	$I_E = 100\text{ }\mu\text{A}, I_F = 0$	BV_{ECO}	All	7			V
Leakage Current Collector to Emitter	$V_{CE} = 10\text{ V}, I_F = 0$	I_{CEO}	H11AA1,3,4			50	nA
			H11AA2			200	
Capacitance Collector to Emitter	$V_{CE} = 0, f = 1\text{ MHz}$	C_{CE}	All		10		pF
Collector to Base	$V_{CE} = 0, f = 1\text{ MHz}$	C_{CB}	All		80		pF
Emitter to Base	$V_{CE} = 0, f = 1\text{ MHz}$	C_{EB}	All		15		pF

Transfer Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Characteristics	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Current Transfer Ratio, Collector to Emitter	$I_F = \pm 10\text{ mA}, V_{CE} = 10\text{ V}$	CTR_{CE}	H11AA4	100			%
			H11AA3	50			
			H11AA1	20			
			H11AA2	10			
Current Transfer Ratio, Symmetry	$I_F = \pm 10\text{ mA}, V_{CE} = 10\text{ V}$ (Figure.8)		All	.33		3.0	
Saturation Voltage Collector to Emitter	$I_F = \pm 10\text{ mA}, I_{CE} = 0.5\text{ mA}$	$V_{CE(SAT)}$	All			.40	V

Isolation Characteristics

Characteristic	Test Conditions	Symbol	Min	Typ	Max	Units
Package Capacitance input/output	$V_{I-O} = 0, f = 1\text{ MHz}$	C_{I-O}		0.7		pF
Isolation Voltage	$f = 60\text{ Hz}, t = 1\text{ min.}$	V_{ISO}	5300			VAC(RMS)
Isolation Resistance	$V_{I-O} = 500\text{ VDC}$	R_{ISO}	1011			Ω

Fig. 1 Input Voltage vs. Input Current

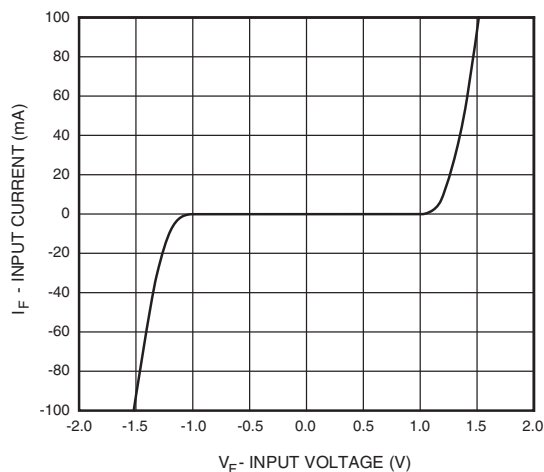


Fig. 2 Normalized CTR vs. Forward Current

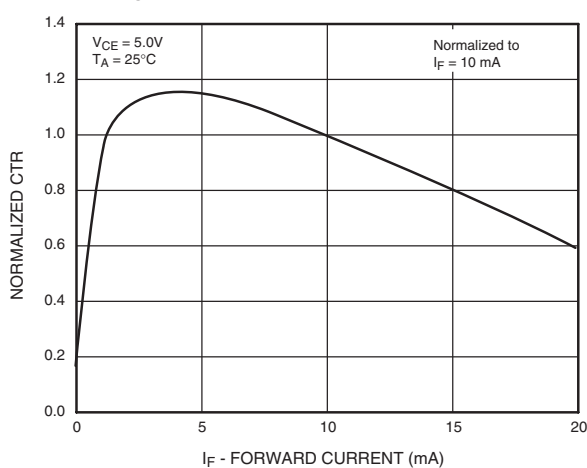


Fig. 3 Normalized CTR vs. Ambient Temperature

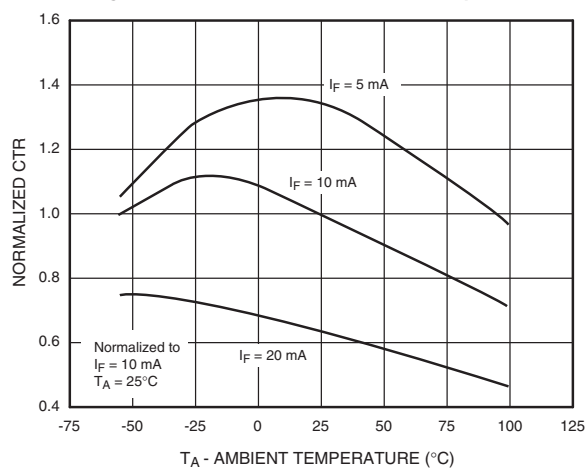


Fig. 4 CTR vs. RBE (Unsaturated)

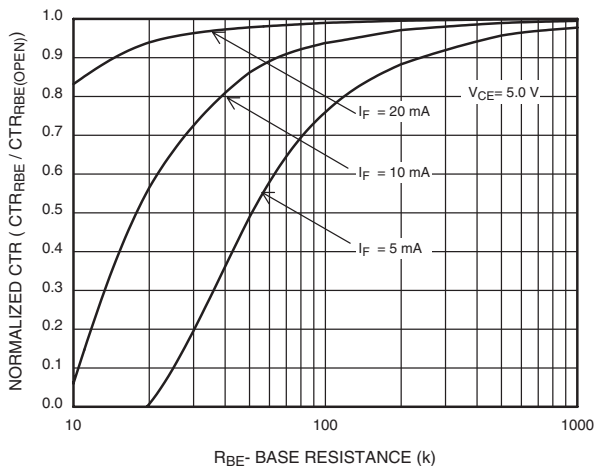


Fig. 5 CTR vs. RBE (Saturated)

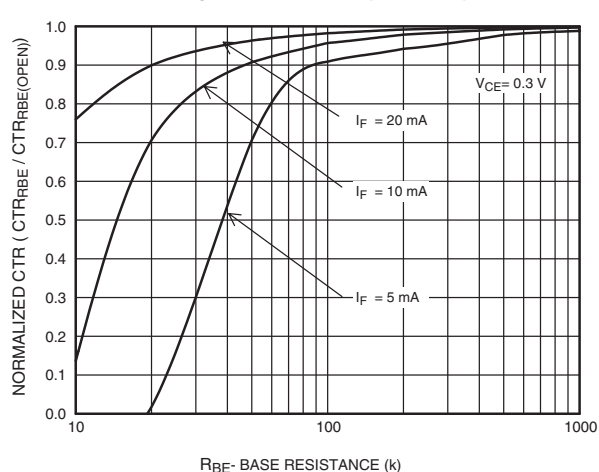


Fig. 6 Collector-Emitter Saturation Voltage vs. Collector Current

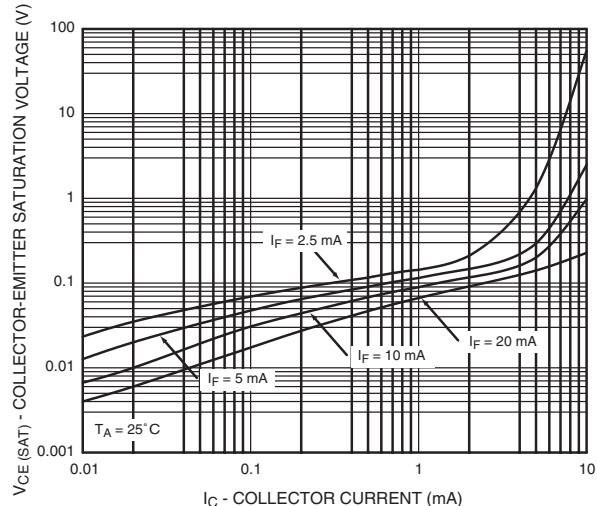
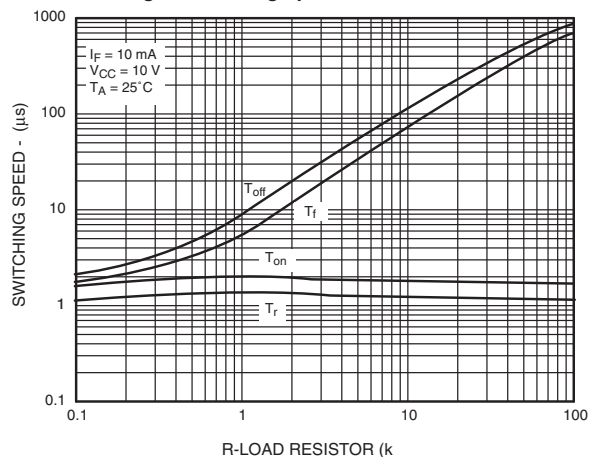
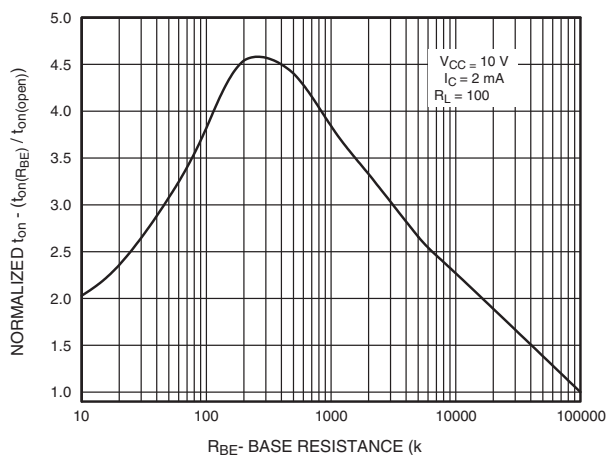
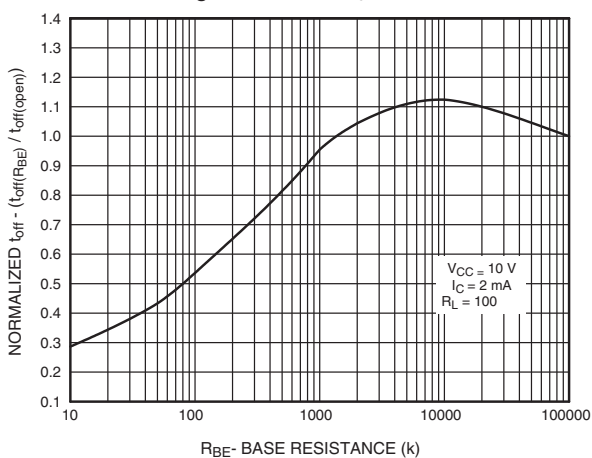
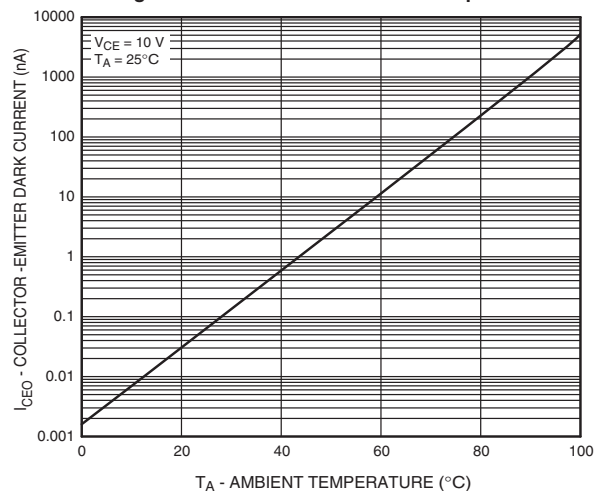
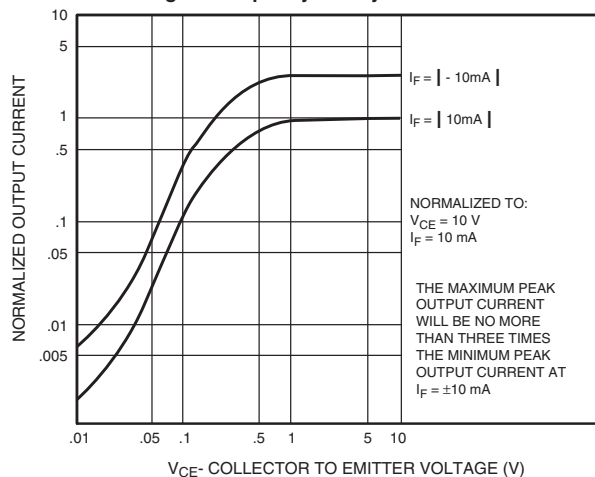
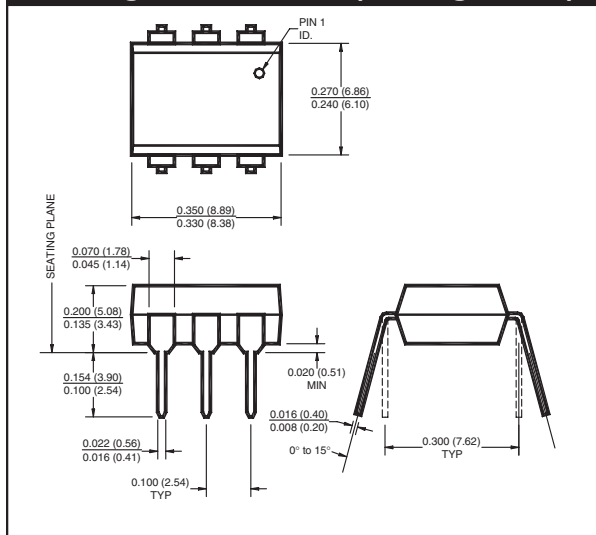
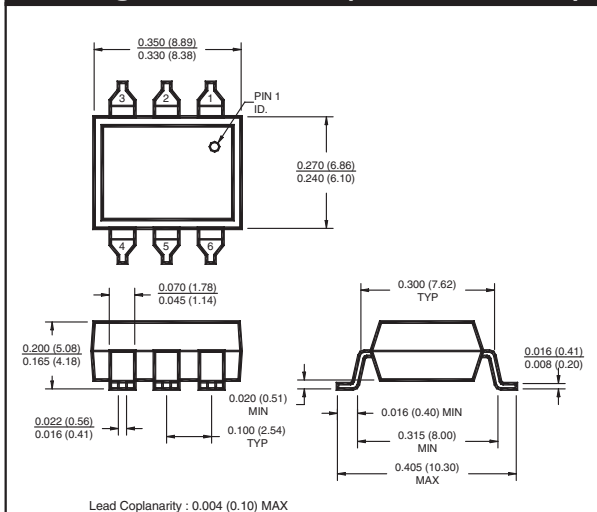


Fig. 7 Switching Speed vs. Load Resistor

Fig. 8 Normalized t_{on} vs. R_{BE}

Fig. 9 Normalized t_{off} vs. R_{BE}

Fig. 10 Dark Current vs. Ambient Temperature

Fig. 11 Output Symmetry Characteristics


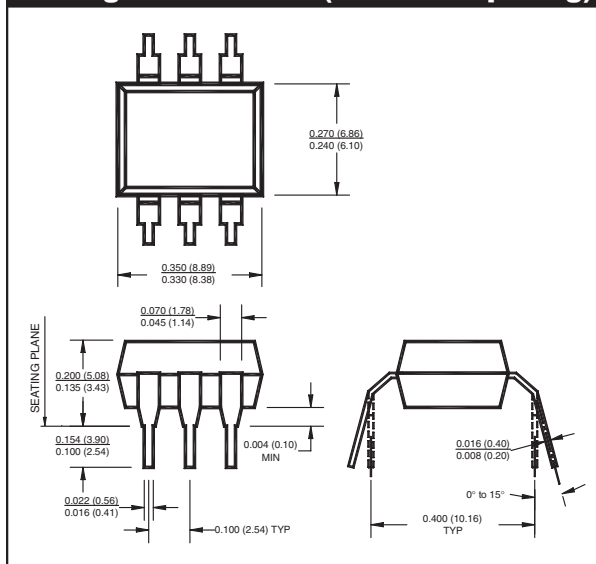
Package Dimensions (Through Hole)



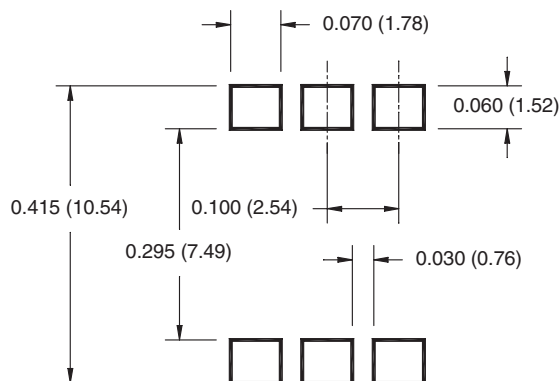
Package Dimensions (Surface Mount)



Package Dimensions (0.4"Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



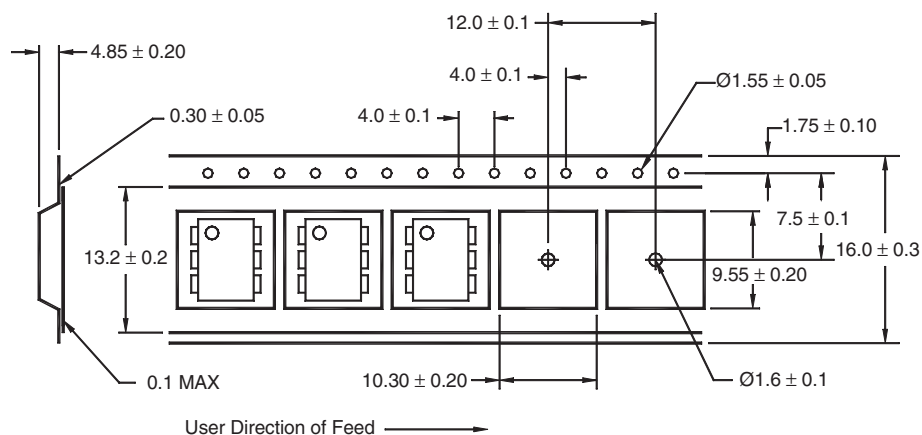
Note

All dimensions are in inches (millimeters)

Ordering Information

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and Reel
W	.W	0.4" Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4" Lead Spacing
3S	.3S	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape and Reel

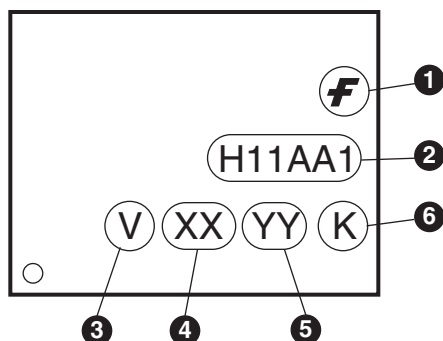
Carrier Tape Specifications ("D" Taping Orientation)



Note

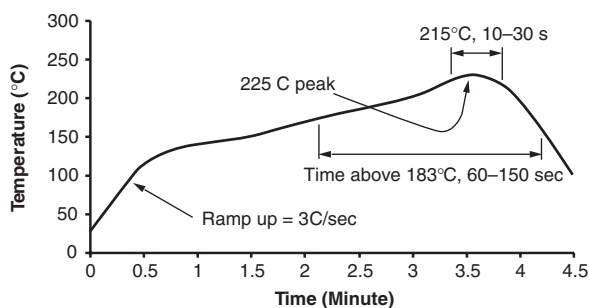
All dimensions are in millimeters

Marking Information



Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	Two digit year code, e.g., '03'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Reflow Profile (Black Package, No Suffix)



- Peak reflow temperature: 225°C (package surface temperature)
- Time of temperature higher than 183°C for 60–150 seconds
- One time soldering reflow is recommended

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E ² CMOST™	i-Lo™	OCX™	μSerDes™	VCX™
EnSigna™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER [®]	Wire™
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Programmable Active Droop™		Power247™	SuperSOT™-3	
		PowerEdge™	SuperSOT™-6	

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Definition of Terms

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Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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